

A Study of the Different Melting Behavior in Pentane and Heptane Monolayers on Graphite

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ABSTRACT

Molecular dynamics simulations are utilized to study the melting transition in pentane (C_5H_{12}) and heptane (C_7H_{16}), physisorbed onto the basal plane of graphite at near-monolayer coverages. Through use of the newest, optimized version of the anisotropic united-atom model (AUA4) to simulate both systems at two separate coverages, this study provides evidence that the melting transition for pentane and heptane monolayers are significantly different. Specifically, this study proposes a very rapid transition from the solid crystalline rectangular-centered (RC) phase to a fluid phase in pentane monolayers, whereas heptane monolayers exhibit a slower transition that involves a more gradual loss of RC order in the solid-fluid phase transition. Through a study of the melting behavior, encompassing variations where the formation of gauche defects in the alkyl chains are eliminated, this study proposes that this gradual melting behavior for heptane monolayers is a result of less orientational mobility of the heptane molecules in the solid RC phase, as compared to the pentane molecules. This idea is supported through a study of a nonane monolayer, which gives the gradual melting signature that heptane monolayers also seem to indicate. The results of this work are compared to previous experiment over pentane and heptane monolayers, and are found to be in good agreement.

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I. INTRODUCTION

The study of thin films of physisorbed molecules has been a topic that has received a significant amount of both experimental and theoretical attention in the past few decades. The importance of these types of systems is becoming more realistic as the technology to probe and study them on an increasingly small length scale evolves in concert with computing performance which permits larger and longer simulations to study that which is still not observable through even some of the most detailed experimental work.

One particular topic that has received a significant amount of attention and interest drawn toward it has been the adsorption of *n*-alkanes onto the basal plane of graphite. Since the *n*-alkanes are fundamental constituents of many products and substances that are very important for industrial and technological application, this family of molecules is at the forefront of many surface applications that range over topics that involve detergency, adhesion, lubrication, and many other similar applied fields. An understanding of the short-chained alkanes on a surface is sought due to their well-known lubrication and adhesion properties, which provides insight into better lubricants and adhesives for industrial use. Furthermore, the *n*-alkanes have been found to be fundamentally important in theoretical studies of more complex systems, such as lipid bilayers,¹⁻² whose intramolecular motions occur over very long time scales which make these complex systems very arduous to simulate. Therefore, what is currently understood about this family of molecules in physisorbed systems has proven to play a significant role in the understanding of many surface systems and surface problems, and one can only imagine where a full understanding of the behavior of these *n*-alkanes on surfaces will lead in the future.

The systems involved in this work deal with primarily two short-chained *n*-alkane molecules, pentane (C₅H₁₂ or C5) and heptane (C₇H₁₆ or C7), physisorbed onto the basal plane of graphite at two previously experimentally determined and studied coverages that are near to full monolayer completion. To further study the effects of chain length, nonane (C₉H₂₀ or C9) monolayers are studied since their phase behavior is similar to that exhibited by pentane and heptane monolayers. Due to its attractive

properties and its popularity in previous experimental work, graphite is utilized for the substrate in this study. The importance of physisorbed *n*-alkanes on graphite is emphasized by the vast experimental effort in recent years³⁻¹⁰ to study the solid and liquid-state behavior in such systems. These studies have found that for even-numbered short-chained *n*-alkanes³⁻⁵, with $n < 12$, the monolayer arranges in a low-temperature herringbone (HB) phase that is commensurate with the substrate (except for butane, which is not found to exhibit a HB phase). Upon heating, these studies report that an intermediate phase, where a solid phase coexists with a liquid, forms until the monolayer undergoes a melting transition. In the case of pentane, this coexistence region is found to be quite small, and the melting temperature of the coexisting monolayer is found to be very near to the bulk melting temperature.

Unlike the short-chained even *n*-alkanes, the odd alkanes⁵⁻¹⁰ show significantly different low-temperature solid phase behavior. Where the even alkanes form a low-temperature HB phase, the odd alkanes form a low temperature rectangular-centered (RC) phase that is at least partially commensurate with the graphite substrate. In particular, the study by Matthies⁶ studies the C5 and C7 monolayers through X-ray and neutron diffraction at reported coverages of 1.01 and 0.98 monolayers respectively. This study finds the RC phase present, but proposes that there is ambiguity in the diffraction patterns regarding fits involving a slightly rotated HB phase. With aid of temperature dependent diffraction patterns, this study observes a shift in the Bragg peak diffraction data that is interpreted as the melting transition, and it is observed that this transition is very rapid and occurs between ca. 99-105K. For C7 on graphite, this study finds that the monolayer seems to undergo a more augmented coexistence region than that observed for C5, with a melting transition occurring at about $T=170\text{K}$ for the 0.98 monolayer sample. In both cases, a proposed model with a slight HB rotation is proposed, and will be utilized for a portion of the simulations in this work.

Further studies of C5, C7, and C9 monolayers⁷⁻¹⁰ involve investigation of the behavior of solid/liquid interface in a multilayer system, as well as a solid monolayer at coverages ranging from submonolayer through completion. In agreement with previous work, this work also indicates that C5 and C7 (as well as C9) crystallize in a solid RC phase at low temperatures. Unit cell parameters are

proposed for submonolayer C5, C7, and C9 through X-ray diffraction patterns, and a high coverage cell is proposed that involves molecules in fully commensurate positions on the graphite substrate that is determined by neutron diffraction of deuterated samples. Furthermore, one study from these authors also indicates “anomalous behavior⁷” in layers of C5, where the solid monolayer does not seem to coexist with a bulk fluid phase, similar to the other *n*-alkane systems studied, but melts very near to the bulk melting temperature of C5. For the purposes of this study, the cell parameters given in [10] that describe a “high coverage” unit cell are used in simulations to study the behavior of a highly commensurate monolayer (that is packed to supercede the intermolecular interaction to the substrate interaction) and compare that to a particular model proposed for 1.01 and 0.98 monolayers of C5 and C7 respectively.

To further underscore the importance and current interest in such systems, the only previous theoretical work that exists (to the authors knowledge) that studies the phase behavior or transitions in physisorbed pentane or heptane is a very recent MD study¹¹ that investigates the behavior of multilayer heptane in an (*NPT*) ensemble. Amongst other behavior reported in this work, the formation of gauche defects is monitored as a function of pressure near the solid-liquid phase transition, and is found to be a significant effect there. The formation of gauche defects as observed by these authors near the solid-liquid phase transition is relevant to this work for reasons that will be discussed in later sections.

Although theoretical studies of odd *n*-alkanes seems to be an topic of future interest, there is a wealth of work that exists over even-alkanes on graphite,¹²⁻¹⁶ with a concentration focused on the study of hexane (C₆H₁₄) in particular. Most notably, the first study over hexane and butane proposes a “footprint reduction” mechanism¹² by which a phase transition is preempted by a space reduction in the monolayer that is a result of intermolecular scattering that supplies kinetic energy allowing the molecules to either tilt out of the surface plane, or else change conformation- in both cases decreasing their in-plane molecular footprint. This theory has been well adapted to these physisorbed systems, and most recent work over monolayer hexane on graphite¹⁶ indicates that melting occurs primarily via the tilting mechanism, with only a very small contribution from gauche defects.

The purpose of this specific work is to study both systems of pentane and heptane monolayers, at two different coverages as to simulate two experimental determinations of a near-monolayer surface coverage, to understand better the phase transitions in these systems. Moreover, both experimental groups that have previously conducted studies over these systems have commented on the “sharpness”⁶ or the “anomalous behavior”⁷ that is observed in the solid-fluid phase transition in pentane monolayers on graphite as opposed to other physisorbed alkane monolayers (such as heptane). Thus, it is the purpose of this work to study how chain length in two physisorbed systems that are extremely similar in their solid phase behavior and have a very similar chain length, can exhibit such different behavior at the melting transition. Furthermore, this study will attempt to classify the phase transitions in terms of phase behavior and calculated thermodynamic quantities and distributions.

The reader should be informed at this point that understanding the phase transitions in monolayers of chain molecules is an arduous task, at best. Early theories of melting (such as the KTHNY theory¹⁷) are generally inapplicable to systems of chain molecules, as more degrees of freedom in the chains allow these molecules to exhibit three-dimensional motion, thus invalidating melting theories for simple 2D systems. Also, a direct study of the phase transition order is also somewhat ambiguous from simulations, as small system sizes can induce a variety of effects on energy fluctuations near the phase transitions which can be quite misleading¹⁸. To even be able to comment on phase transition orders in simulations, one has to consider a finite-size scaling scheme and study how the free energy scales with system size. Although the author acknowledges that this scheme would be extremely important to further our understanding of phase transitions in these monolayers, this work specifically is completed to study the melting behavior independent of order, consistent with the previous studies that have eluded to characterizing melting by the “footprint mechanism” which effectively characterizes melting behavior strictly in terms of molecular behavior, which is more applicable to simulations.

II. MODEL AND METHODS

A. Potential Interactions

Both bonded and non-bonded interactions were modeled in this work. The first of the non-bonded interactions utilized in this work is the adatom-adatom pair interaction, and is modeled by the well known Lennard Jones pair potential function

$$u_{LJ}(r_{ij}) = 4\varepsilon_{ij} \left[\left(\frac{\sigma_{ij}}{r_{ij}} \right)^{12} - \left(\frac{\sigma_{ij}}{r_{ij}} \right)^6 \right]. \quad (1)$$

where ε refers to the well depth of the potential, and σ represents the collision diameter.

Lorentz-Bertholot combining rules:

$$\sigma_{ij} = \frac{\sigma_i + \sigma_j}{2}, \quad \varepsilon_{ij} = \sqrt{\varepsilon_i \varepsilon_j}, \quad (2)$$

are used to describe mixed interactions when particles i and j are of different types.

The other non-bonded potential used is the graphite surface potential, given by a Fourier expansion proposed by Steele¹⁹:

$$u_i^{gr} = E_{0i}(z_i) + \sum_{n=1}^{\infty} E_{ni}(z_i) f_{ni}(x_i, y_i), \quad (3)$$

where

$$E_{0i}(z_i) = \frac{2\pi q \varepsilon_{gr} \sigma_{gr}^6}{a_s} \left(\frac{2\sigma_{gr}^6}{45d(z_i + 0.72d)^9} + \frac{2\sigma_{gr}^6}{5z_i^{10}} - \frac{1}{z_i^4} - \frac{2z_i^2 + 7z_id + 7d^2}{6d(z_i + d)^5} \right), \quad (4)$$

$$E_{ni}(z_i) = \frac{2\pi \varepsilon_{gr} \sigma_{gr}^6}{a_s} \left[\left(\frac{\sigma_{gr}^6}{30} \right) \left(\frac{g_n}{2z_i} \right)^5 K_5(g_n z_i) - 2 \left(\frac{g_n}{2z_i} \right)^2 K_2(g_n z_i) \right], \quad (5)$$

and

$$f_1(x_i, y_i) = -2 \cos \left[\frac{2\pi}{a} \left(x + \frac{y}{\sqrt{3}} \right) \right] - 2 \cos \left[\frac{2\pi}{a} \left(x - \frac{y}{\sqrt{3}} \right) \right] - 2 \cos \left[\frac{4\pi}{a} \left(\frac{y}{\sqrt{3}} \right) \right]. \quad (6)$$

Here g_n is the modulus of the n^{th} graphite reciprocal lattice vector and the K 's are modified Bessel functions of the second kind. The strong holding potential defined by eqn (4) is responsible for the vertical adsorbate-substrate forces and is obtained by summing over an

infinite number of graphene sheets using the Euler-MacLaurin theorem. Likewise, the term in eqn (5) is responsible for the lateral forces on the adsorbate from the substrate, and is obtained by taking only the first graphene layer into account. In a similar fashion, only $f_1(x_i, y_i)$ is defined above because of the rapid convergence of the sum in eqn. (3), and only the $n = 1$ term is sufficient. All parameters for non-bonded interactions are given in Table I.

In this study, both bond-angle bending and dihedral angle bending are considered. Assuming the bond angles to be harmonic, the three-body bending potential can be expressed as²⁰

$$u_{bend} = \frac{1}{2} k_{\theta} (\theta_b - \theta_0)^2, \quad (7)$$

where θ_b is the bond angle, θ_0 is the equilibrium bond angle and k_{θ} is the angular stiffness. The other bonded interaction is the four-body dihedral (torsional) bending, which is of the form²¹

$$u_{tors} = \sum_{i=0}^5 c_i (\cos \phi_d)^i, \quad (8)$$

where ϕ_d is the dihedral angle and the c_i are constants. All parameters for bonded interactions are given in Table II.

B. Simulation Details

A constant temperature, constant planar density, and constant molecule number (N, ρ, T) canonical ensemble molecular dynamics method is used to model pentane (C5), heptane (C7), and nonane (C9) monolayers physisorbed onto the basal plane of graphite. To model the C5, C7, and C9 molecules, the anisotropic united atom (AUA4)²² model is used, which attempts to take into account the presence of hydrogen atoms by distinguishing the methyl (CH₃) groups from the methylene (CH₂) groups by shifting the pseudoatom centers more toward the hydrogen atoms. Unlike the united-atom (UA) model, which does not distinguish the two groups except for by mass, this model more accurately represents the intermolecular interactions present in the system, which is increasingly more important in smaller n -alkane molecules, where the ratio of methyl groups to methylene groups is comparable.

Initially the UA model was used for this study, but a noticeable difference in behavior in the AUA model as compared to the UA model motivated an adaptation of the AUA4 model for this study. It is important to note that there is a significant difference in the behavior of these two models for odd alkane monolayers, which further contributes to recent speculation of such a difference²³ (since the AUA model gives the most “accurate” physical interpretation of an alkane).

To model the temperature dependence of the low-temperature solid phase, experimental determinations of unit cell parameters are used that correspond to *both* cell sizes and orientations given in [6] and [10]. From this data, the model chosen for both C5 and C7 monolayers is presented in table 1, as well as the cell parameters utilized from [10] for C9 that involve a fully commensurate RC phase. Matthies⁶ proposes that one possible scenario for the solid crystalline phase observed involves a slight HB rotation, and after careful consideration of submonolayer cells proposed in [10] that are slightly extended in the *b*-axis direction of the unit cell (which could indicate a HB rotation), this work adopts a slight HB rotation for C5 and C7 monolayers that is reported in table 1 as well.

In all simulations, periodic boundary conditions are used, and temperature control is maintained by a velocity rescaling technique that rescales velocities such that equipartition is satisfied for the center-of-mass, rotational, and internal temperatures (for more detail, refer to [16]). The time step used in all simulations is 1 fs, and all simulations are typically carried out over a period of 700 ps, with the equilibration period spanning over the first 200 ps of the simulation. This equilibration period is found to be more than enough simulation time to achieve a thermodynamic equilibrium. To carry out the integration of the equations of motion, a velocity Verlet RATTLE²⁴ algorithm is utilized, which performs the integration while constraining the bond lengths to an equilibrium value of 1.535Å. The phase behavior is typically sampled in steps of 5K (in some cases 10K), and in steps of 2-3K near phase transitions, to delineate the temperature dependence of the phases and phase transitions.

III. RESULTS

Figure 1 is a visual representation of the phase behavior near and after the melting transition for high coverage monolayers of C5 and C7. Figure 1a represents the behavior of the pentane monolayer, and figure 1b corresponds to the heptane monolayer. Although the different melting behavior is evident from figure 1 for these two monolayers, figure 2 further emphasizes this in a more quantitative fashion. In figure 2, the structural order parameter, OP_n , defined as:

$$OP_n = \frac{1}{N_m} \left\langle \sum_{i=1}^{N_m} \cos n(\phi_i) \right\rangle \quad (9)$$

is presented for all coverages of pentane and heptane monolayers studied, at each temperature point studied. In eqn. (9), ϕ_i is the angle that the smallest moment of inertia axis of molecule i makes with the x -axis of the computational cell. Due to the orientation of the molecular long axes along the y -direction of the cell, the values of $n=2, 4, 6$, and 8 are used to give information regarding the nature of the melting transition, where large values of n are very sensitive to fluctuations and give information on the n -fold symmetry of the solid phase. In general, in the disordered (fluid) phase, the molecular orientations are randomly sampling angles in the substrate plane, so OP_n vanishes in such a case. The temperature dependence of OP_n in figure 2 indicates a relatively sharp transition to a disordered phase in pentane monolayers, whereas heptane monolayers seem to exhibit a melting transition with a more gradual nature.

The next two figures, figure 3 and figure 4, both compliment each other in the behavior that they indicate. In figure 3, the atom-atom pair correlation function, $g(r)$, is defined to a cutoff of $30\text{\AA}$. In general, the atomic pair correlation function indicates the probability of finding a neighboring atom, j , a pair distance r from a central atom, i . This function is used as a measure of the (quasi) long-range order associated with the solid crystalline phase, and thus acts as a measure of the melting transition in the monolayer. Whereas the atomic pair correlation function gives probabilities of neighboring atoms at particular pair distances, the center-of-mass bond-orientational distribution, $P(a)$, gives the probability of the center-of-mass of a neighboring molecule j , being a particular orientational angle a , from a central

molecule i . Thus, these two quantities characterize the studied monolayers in terms of both translational and orientational order, which can properly characterize the structural behavior of the monolayer. In general, one observes that near the melting transition (where the melting temperatures are indicated in table 4), a sudden loss of (quasi) long-range translational and orientational order ensues for the pentane monolayers, but a more gradual loss of order seems to be the case for the heptane monolayers. This will be further discussed in the following section.

Figure 5 presents the three-dimensionally averaged static structure factor defined as:

$$S(q) = 1 + \int_0^{\infty} (g(r) - 1) \frac{\sin(qr)}{qr} r dr. \quad (10)$$

This function is obtained directly from the atomic pair correlation function, $g(r)$. This quantity is defined in figure 5 for monolayers of C5 and C7 that are simulated initially with a slight HB rotation, thus corresponding to data in [6]. In general, this quantity provides important information in reciprocal space that can be directly linked to the observed diffraction data by Matthies⁶.

In addition, figure 6 provides a measure of the specific heat at constant area (C_A) for all monolayers studied in this work through the square fluctuations in the energy. It is characteristic for a first order phase transition to indicate a very distinct peak in the specific heat at the phase transition (although, finite size can play a significant role in the interpretation of this thermodynamic quantity). From figure 6, it seems to be the case that the melting transition for the pentane monolayers indicates a fairly distinct peak in the specific heat, whereas the heptane monolayers indicate a broad region of energy fluctuations near the phase transition. In addition, this quantity is very useful in determining the melting transition temperatures in terms of energies (rather than structural properties) for the tabulated melting temperatures presented in table IV.

Figures 7 and 8 both indicate the presence of gauche defects in the studied C5 and C7 monolayers. Figure 7 is a representation of the average dihedral energy per molecule, which is indicative of the presence of gauche defect formation in each monolayer. If all molecules assume a strict trans conformation, then the average dihedral energy takes on a value of 0, whereas higher average dihedral

energies correspond to (primarily) the more significant presence of gauche defects in the monolayer. In addition to figure 7, the dihedral angle distribution is plotted in figure 8, where the two possible gauche defects correspond to $\phi_d = 180 \pm 120^\circ$. Both of these quantities seem to indicate a very distinct difference in the dihedral behavior for the C5 and C7 monolayers.

Figure 9 presents the temperature dependence of OP_n (as defined previously) for two “variations” to study and compare to figure 2. The first case is where the constants in the dihedral potential are completely eliminated, in order to study the dependence of the melting behavior on these gauche defects. To eliminate the formation of gauche defects, the constants in the dihedral potential (presented in table II) are increased by 10X, in order to make the trans-gauche barrier much higher, and thus force the molecules to stay in a trans conformation. This variation is presented for fully commensurate C7 monolayers, and is plotted over an identical temperature region as is presented in figure 2. The second case corresponds to the temperature dependence of OP_n for a fully commensurate C9 monolayer (whose alkyl chain contains two more methylene groups than C7). From this, one notices the gradual melting behavior for C9 monolayers, which is visually represented through a series of snapshots at labeled temperatures in figure 10. Comparing figure 10 to figure 1b, one notices striking similarities, which will be discussed in the following section.

Finally, to support the different melting behavior in the C5 and C7 monolayers, the average corrugation potential energy per psuedoatom defined as:

$$\langle U_1 \rangle = \frac{1}{N_m} \left\langle \sum_{i=1}^N E_{1i}(\vec{r}_i) \right\rangle, \quad (11)$$

is plotted vs. temperature for the fully commensurate C5 and C7 monolayers. This quantity indicates a very rapid loss of (atomic) commensurability with the substrate for the C5 monolayer, but a more gradual loss of such commensurability for the C7 monolayer, which emphasizes the difference in the melting behavior for each monolayer with respect to the substrate.

IV. DISCUSSION

This section will be split into two separate subsections. The first section will discuss the very distinct differences in the melting behavior in the C5 and C7 monolayers as is indicated through figures 1-6, and will compare these results to experiment. The latter section extends upon the observations from the first section, and goes a step further to propose why this melting behavior takes place in such a different manner for the C5 and C7 monolayers through variations of (i) the dihedral potential constants, and (ii) the alkyl chain length (i.e. simulating C9 monolayers, whose solid phase behavior is the same as C5 and C7 monolayers). Finally, comparisons to experimental work involving systems of physisorbed alkanes with a longer chain length are presented.

A. Melting in Pentane and Heptane Monolayers

In general, figures 1 through 6 all seem to suggest different melting behavior in C5 and C7 monolayers. One can visually inspect the snapshots presented in figure 1 and come to this conclusion. In figure 1a, the nature of the melting transition for C5 monolayers is evidently different than that presented in figure 1b for C7 monolayers with the molecules all arranged in fully commensurate positions (thus representing the cell parameters given in [10]). At temperatures ca. 5K below the monolayer melting temperature, it seems from figure 1a that the majority of the C5 molecules are still commensurate with the substrate, however, there are some molecules that have lost the orientation of their long-axes with respect to the y-axis of the computational cell, but not as to disturb the order of the RC solid phase that is present. However, when looking at the several snapshots presented in figure 1b, this behavior is not observed. In fact, it seems as if ca. 40K below the melting temperature ($T=180\text{K}$), that the molecules in the monolayer seem to “slide” along the direction in which their long-axes point. Analyzing the next two snapshots, which are taken to be below the melting temperature, one notices that this “sliding” becomes more significant as the temperature is increased. In particular, ca. 20K below the melting temperature, the result of this translational motion of the molecules along the y-axis direction of the computational cell is that the sublattices in the monolayer seem to take on an “S” shape. A snapshot of the solid phase

behavior at $T=215\text{K}$ suggests that this translational motion eventually causes the molecules to disorder with respect to the substrate, but still assume the “lamellar” type of sublattice structure that is observed at lower temperatures on a short length scale. It should be noted that this type of “sliding” behavior has been previously observed through scanning-tunneling microscopy (STM) experiment for longer alkanes²⁵, so this effect could largely be due to an increased chain length of the C7 with respect to the C5.

Further comparison of the melting behavior of these two monolayers, considering both coverages studied, can be made through figures 2 and 6. In figure 2, the order parameter, OP_n , is utilized for $n=2, 4, 6$, and 8 to give detailed information regarding how the phase transitions take place, and what fluctuations are present in the molecular orientations with respect to various axes of the computational cell. In general, comparing the coverages proposed by Matthies⁶ with a slight herringbone (HB) rotation, one notices a very stark difference between the melting behavior in the two monolayers. For the C5 monolayer at this coverage, the values of OP_n seem to suggest a consistent trend (not fully aligned with the y-axis, but involving some rotation, which is what this model⁶ proposes), but at 92K, all four monitored order parameters quickly vanish, suggesting a very sudden loss of order. The behavior of the C7 monolayer with a slight HB rotation⁶ shows a very different trend. In fact, the values of OP_2 represent a slight deviation from an orientation fully aligned with the y-axis of the computational cell, but probably not a full 6° as was utilized as the initial condition. At ca. $T=140\text{K}$, a loss of order in OP_2 begins until melting, which seems to occur in simulations at ca. 180K. OP_4 seems to indicate the same type of behavior, and the other two order parameters OP_6 and OP_8 indicate significant fluctuations present even at low temperatures. This elucidates the nature of the phase transition in both monolayers at this coverage as being significantly different.

In comparison, figure 2 also includes OP_n for the high coverage monolayers¹⁰ studied. For these monolayers, analogous behavior seems to be apparent, but not as emphasized as in the other two monolayers. In particular, for high coverage C5 monolayers, OP_2 seems to be very close to its minimum in the solid phase until ca. 130K, where a small deviation seems to arise and persist until 140K. Between 140K and 145K, there is a significant loss of orientational order and all order parameters, OP_n , become

vanishingly small between ca. 145-150K. Although this phase transition isn't as abrupt as that observed for the other⁶ C5 monolayer, it still occurs over a temperature region of ca. 5K which is very short in comparison to that of C7. In general, the small deviation from the minimum OP_2 value could be caused by phase behavior representative of that shown in the middle panel of figure 1a, where there are some molecules that lose order with respect to the substrate, but the majority of the C5 molecules tend to keep strict commensurate positions, hence still having their long-axes completely oriented with the y-axis of the computational cell. In comparison, the high coverage C7 monolayer seems to indicate the same type of phase behavior as was observed for the previous coverage studied, except again, maybe not as exaggerated. However, all order parameters seem to indicate the beginning of a gradual loss of order between ca. 190-195K, which continues until ca. 220K which is the approximate temperature that simulations suggest that melting takes place.

In addition to these order parameters, which are excellent indicators of structural behavior near the melting transition, energetics can also be used to determine the melting behavior. In particular, the specific heat at constant area, C_A , (the analogous specific heat at constant volume for a 2-D thin film) can be utilized to understand the nature of the phase transition. Inspection of figure 6 indicates many of the features that have been presented in OP_n in figure 2. In general, the phase transitions for the C5 monolayers studied seem to have a very sharp peak in C_A , with a bit of broadening in this peak for the high coverage monolayer¹⁰ as compared to the monolayer proposed by Matthies⁶, which is consistent with the behavior observed in OP_n . In contrast, both C7 monolayers seem to have very broad peaks in the temperature dependence of C_A , indicating that the fluctuations in the energy that are representative of a phase transition take place over a significant temperature range. This underlines the different melting behavior in C5 monolayers as compared to C7 monolayers, for both coverages studied.

Figures 3 and 4 represent the atom-atom pair correlation function, $g(r)$, and the center-of-mass bond-orientational distribution for the 1st-5th neighbors. From the temperature dependence of both of these figures, one can notice that, in general, the loss of long range orientational order (from figure 4) as well as the loss of long range order with respect to atomic pair distances (from figure 3) seems to

diminish gradually for C7 monolayers, as compared to very rapidly for C5 monolayers. The results in these figures presents a complimentary perspective of correlations in the monolayer that indicate the same difference in melting that is evident from order parameters and energies.

Also, from figure 5, and calculated from the pair correlations presented in figure 3, the three-dimensionally averaged static structure factor is shown for C5 and C7 monolayers that are simulated based upon unit-cell parameters given by Matthies⁶. The calculation of this quantity gives a direct comparison to the experiment⁶, which is important to support that simulations are truly representing experimentally observed behavior. In particular, these can be directly compared to the figures presented by Matthies⁶ that give a direct temperature dependence near and after the melting transition for C5 and C7 monolayers. Comparison of the calculated temperature dependence of the static structure factor for the C7 monolayer indicates excellent agreement of the peaks at ca. $q=1.45\text{\AA}^{-1}$ and $q=1.18\text{\AA}^{-1}$. The broadening of the $q=1.45\text{\AA}^{-1}$ peak at about 180K is also in excellent agreement with the temperature dependence shown in experiment, where there is a slight broadening between $T=175\text{K}$ and $T=180\text{K}$ of the peak intensity. Also, the slight shift in this peak toward higher q as the temperature is increased toward melting is also in very good agreement. Further comparison of the C5 monolayer indicates less fair agreement in this aspect, although good qualitative agreement. First of all, due to the diverging nature of the integral performed to obtain $S(q)$ in this study, peaks at low- q (below what is shown) can not be readily compared to experiment. In this case, the peak at higher q (corresponding to q slightly higher than $1.4\text{\AA}^{-1}$) in figure 5-5 occurs about $q=1.5\text{\AA}^{-1}$, but still indicates the same qualitative behavior of the temperature dependence given by Matthies of the peak labeled (11), with a very sharp decrease of intensity at the melting transition (which occurs between 99-105K in experiment, compared to 92K in simulations), and a pretty consistent peak positioning through all temperatures. Also, simulations indicate that there are three peaks below this (11) peak, and experiment predicts only one such peak. However, the rapid disappearance of the distinctive nature of all peaks at temperatures between 90-95K is in agreement with experimental observations of such behavior between temperatures of 99-105K. Therefore, the behavior of C5 on graphite at these simulated coverages is in qualitative agreement with

experiment from calculated structure factors, but not to the degree in which C7 monolayers are. Although, it is important to note that the intensities of the peaks in experiment⁶ decrease very rapidly, and Matthies does comment on the “sharpness” of the phase transition in the C5 monolayer, which is what is observed in this study.

Finally, based upon order parameters, specific heats, and other quantities that have been presented to this point, the melting temperature of each monolayer is proposed, with respective uncertainty, and a comparison of experimentally observed melting temperatures in table IV. In general, one observes that the AUA4 model (in all four cases) gives a pretty good representation of the melting transition based upon the melting transitions.

Therefore, from the study presented thus far, one is left with a picture for the melting transition that is significantly different for monolayers with molecules that have only one difference that resides in their chain length. Therefore, the next section of this chapter is devoted to understanding the origin of this gradual phase transition for C7 monolayers compared to the sharp transition observed in C5 monolayers. Two separate variations are performed to study (i) the role of gauche defects, which seem to be present in the C7 monolayer, but not the C5 monolayer, and (ii) the role of chain length, by studying how the trends that have been observed in melting thus far evolve with a monolayer consisting of a longer-chained alkane, nonane (C_9H_{20}).

B. Gauche Defects and Nonane Monolayers

From inspection of figure 1, one notices that near the melting transition in the C7 monolayer, there are several C7 molecules that exhibit gauche defects about their endgroups (mostly) and some centralized gauche defects as well. However, when comparing this gauche defect formation near melting in the C7 monolayer to that near melting in the C5 monolayer, one finds that the C5 monolayer exhibits very few (if any) gauche defects in the C5 alkyl chains. Therefore, since C7 is a longer chain molecule, it has more available degrees of freedom that allow more gauche defects to form in the chains. Based upon this reasoning alone, one would initially propose that, since the *only* difference between C7 and C5 is that

one has a longer chain length than the other, then it must be that this different phase transition behavior is generated by the increased number of gauche defects in the monolayer.

To further analyze this idea, figures 7 and 8 involve quantities that indicate the formation of gauche defects in the monolayer. In figure 7, the average torsion energy per molecule is presented as a function of temperature for C5 and C7 monolayers. It is quite evident that there is more energy partitioned into the torsional degrees of freedom in monolayers of C7 as compared to C5. In fact, both coverages of C7 monolayers studied seem to have a non-linear increase in the average dihedral energy as the temperature is increased, whereas C5 monolayers seem to mostly indicate linearity in the temperature dependence of this average energy. This can be further analyzed by studying the dihedral distributions presented in figure 8. In this case, the dihedral distributions are taken at the simulated temperature point *directly* before the proposed melting temperature in table IV, to indicate the presence of gauche defects near melting in each monolayer. The appearance of peaks at $180 \pm 120^\circ$ indicates a significant formation of gauche defects in the monolayer. In analogy to figure 7, therefore, it is no surprise that both C5 monolayers indicate no presence of the gauche peaks, indicating vanishingly small, if any, presence of gauche defects in the monolayers. However, both C7 monolayers seem to indicate some gauche defect formation, with more gauche defects observed in the high coverage monolayer (which isn't surprising either, since the formation of gauche defects is largely coupled to intermolecular scattering, and this coverage is the one in which there is the most molecular packing). Therefore, this justifies that there are a significant number of gauche defects in the C7 monolayer and there are very few, if any, in the C5 monolayer near the melting transition.

At this point, it is reasonable to wonder if the formation of gauche defects actually contributes to the melting behavior that is emphasized in the previous section. In fact, to study this, the formation of gauche defects is completely eliminated in the high coverage C7 monolayer by increasing the dihedral potential constants by an order of magnitude, and a conducting a series of simulations at several temperature points. To compare the results of this variation with those of the normal high coverage C7 monolayer, order parameters OP_n are calculated and presented in figure 5-9 (top panel). The temperatures

are scaled such that the temperature ranges of both high coverage monolayers (i.e. the one in figure 2) are identical, so one can compare how the gradual behavior near the melting transition changes by negating the formation of gauche defects. In fact, a very close comparison indicates that there is a *small* difference in such gradual melting behavior, but it is not one that is extremely apparent. Also, in correspondence to work over hexane monolayers¹⁶, it is interesting to note that the melting temperature of the monolayer is increased by ca. 60K when such elimination of gauche defects is performed. This indicates that gauche defects largely play a role in the melting transition in this system through the footprint mechanism¹², but such is not the focus of the study by performing such a variation in this case. However, due to the gradual nature of the melting transition when gauche defect formation is eliminated, one can *not* conclude that the formation of gauche defects is the reason for the gradual loss of order that comes about in the phase transition exhibited by C7 monolayers, even though both studied C7 monolayers inherently rely upon gauche defects for the melting transition, whereas the C5 monolayers show little or no sign of gauche defects near the melting transition. However, it seems as if the gradual nature of melting is slightly less apparent (comparing to figure 2), but the melting transition with no gauche defect formation for the C7 monolayer does not exhibit any sign of sharpness, which would be the case if gauche defects were, in fact, the sole reason for the gradual melting behavior in C7 monolayers compared to C5 monolayers.

The last variation that is completed in this work involves increasing the length of the alkane chain (from that of a C7 molecule), to study what effect this has on the melting transition. Therefore, a study of a nonane monolayer at several temperature points (with simulation times identical to those of C7 and C5 monolayers, and initial conditions presented in table 1) is conducted to comment on evolving trends that occur near melting when the chain length is increased. Since it is previously evident that gauche defects do not play the lead role in this gradual melting behavior, despite the differences presented for the C5 and C7 monolayers, the only other way in which C5 and C7 differ is just simply in chain length. Therefore, the study of C9 monolayers introduces a difference between the C7 and C9 monolayers that is identical to the difference in C5 and C7 monolayers. In particular, figure 9 and 10 indicate the same type of behavior as that reported in C7 monolayers. In figure 9 (bottom panel), the order parameters OP_n are calculated to

indicate melting from a structural perspective. One notices that the nature of the trends exhibited in this figure is very similar to those presented for (high-coverage) C7. Furthermore, a series of snapshots is presented in figure 10, which *also* shows the same type of slow gradual loss of order in the monolayer which first involves a loss of strict translational order through sections of molecules in the solid RC phase sublattices “sliding” along the y-axis direction of the computational cell.

This observation of the behavior of the nonane monolayer suggests that this sliding must be an inherent type of behavior that arises near the melting transition in monolayers where the components have a significant chain length. When studying the low-temperature solid phase of the odd-alkanes, with all the molecules packed together, the author speculates (based on order parameters and presented snapshots) that C5 has a short enough chain length that it can mobilize and disorder when the substrate-molecule interaction subsides to thermal fluctuations in the monolayer which tends to disorder the monolayer. However, for longer alkanes (C7 and nonane), due to the significant chain length that tends to conform the molecules to the lamellar-like structures observed for the odd alkanes¹⁰ on graphite, at temperatures where thermal fluctuations start to play a role in the monolayer, the molecules tend not to disorder by changing their long-axis orientations (since they are packed in the lamellae, they can not do so without a very large amount of energy), but rather tend to undergo translational motion. During this translational motion, the molecules will tend to “collide” with neighbors in other lamellae, which will tend to create gauche defects about the endgroups of the molecule chains, which largely contribute to melting by the footprint reduction (which can explain the large dependence of the melting transition on the formation of gauche defects that is observed for (high coverage) C7 monolayers when dihedral variations are carried out on the monolayer).

In fact, this speculation can be somewhat justified by analyzing the average corrugation potential energy per psuedoatom for (high coverage) monolayers of C5 and C7 in figure 11. C5 monolayers seem to indicate a very sharp loss of atomistic commensurability with the substrate, but C7 monolayers seem to exhibit a more gradual loss. It seems as if there is strong commensurability in the C5 monolayer up until a point (ca. 145K) where a loss of atomic order with respect to the substrate corrugation takes place and

melting occurs. However, the loss of atomic order with the substrate for C7 monolayers is a gradual process, slowly occurring over those temperature points that approach 220K. This is the type of behavior that would be expected if the C7 molecules actually were going through such a disordering process (facilitated by translational motion) at temperatures leading up until the melting transition. Therefore, this work proposes that this difference in melting behavior is due only to chain length, and as much as gauche defect formation does provide the footprint reduction needed for the phase transition to take place, the gradual melting transition that is observed for C7 monolayers comes from the packing in the monolayer, and the decreased lack of mobility of the molecule due to the increased chain length from C5.

Further analysis of the nonane monolayer seems to indicate the same type of melting behavior, which tends to further justify that this effect is largely due to chain length. Furthermore, the understanding of this translational behavior near the melting transition due to chain length could largely explain phase behavior prior to melting in larger alkanes on different surfaces. Besides this type of sliding being observed in STM images of C25 and C50 in previous work²⁵, alkanes with lengths as large as C60 on graphite²⁶, and alkanes such as C44 on Cu(100) and Cu(110)²⁷ have been observed to exhibit this lamellar type of solid phase behavior. Hentschke et al²⁵ propose that the solid phase in longer alkanes on graphite involves “rod-like” molecules on the surface, without the “coiled” molecular behavior that is observed in the bulk fluid. In fact, simulations in this particular study seem to suggest similar behavior, and due to the strict solid RC phase, the C7 and C9 monolayers are confined to move only along their long-axes, thus causing “sliding.” In this sense, this type of behavior exhibited for C7 and C9 seems to be in registry with what has been observed in longer alkanes in previous experiment. Therefore, it is interesting to note the similarities that the monolayers studied in this work seem to have with longer alkane monolayers that have been previously studied, and furthermore, it is equally interesting to understand how the behavior of the monolayers near the melting transition seems to change (with increased chain length), which seems to result from only the longer chain length of the physisorbed monolayer in the solid RC phase, which tends to “stifle” the molecules to only move along their long-axis direction.

V. CONCLUSIONS

The study presented in the previous sections brings some very key conclusions to the behavior of C5 and C7 monolayers near the melting transition, in correspondence with two previous experimental studies. In particular, this study proposes the following conclusions: (i) The melting behavior in monolayers of C5 and C7, physisorbed onto the graphite basal plane, indicate significant differences. In particular, this study finds that the melting transition for C5 monolayers involves a very sharp loss of order with respect to the substrate, whereas the melting transition for C7 monolayers seems to be one of a very gradual nature. This is in good agreement with the “anomalous behavior”⁷ and the “sharpness”⁶ observed experimentally for C5 monolayers. (ii) On the basis of comparison of the C5 and C7 monolayers, the differences between C5 and C7 (namely, the difference in torsion and chain length) are varied to study how each contributes to the “gradual” behavior of the melting transition. This study proposes that it is *not* an increased presence of gauche defects that is responsible for this difference in melting behavior (as one may initially assume), but rather it is the increased chain length that “stifles” the orientational disorder of the longer molecule, which contributes to this gradual melting behavior for the longer adsorbed molecules. (iii). This study proposes melting behavior (with respect to melting temperatures) that seems to be in good agreement with experiment. This is the first study conducted regarding the solid-state behavior of physisorbed alkanes with the new AUA4 model, and thus validates its use for further studies over these types of systems. (iv) Finally, the translational motion prior to melting exhibited by C7 and C9 monolayers is in agreement with that presented in previous experimental studies, indicating that this melting behavior could be inherent to many more physisorbed alkanes on surfaces (whose phase behavior consists of ordered lamellae). Furthermore, whereas previous understanding of melting comes from a “space reduction,”¹² it is possibly more informative to understand this “sliding” type of behavior at high temperatures prior to melting, as it is *because* of this sliding that gauche defects form in the physisorbed molecules, which provides the space reduction needed. Therefore, this sliding behavior could present a more fundamental understanding of the melting behavior

in these monolayers than “space reduction,” which ultimately seems to be a consequence of the observed translational motion.

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TABLES AND FIGURES

Table I. Non-bonded potential parameters used in the simulations.

Parameter	Value
$\epsilon_{\text{CH3-CH3}}$	120.15 K
$\sigma_{\text{CH3-CH3}}$	3.6072 Å
$\epsilon_{\text{CH2-CH2}}$	86.291 K
$\sigma_{\text{CH2-CH2}}$	3.4612 Å
Q	2
a_s	5.24 Å ²
D	3.357 Å
ϵ_{gr}	44.89 K
σ_{gr}	3.66 Å

Table II. Bonded potential parameters used in the simulation.

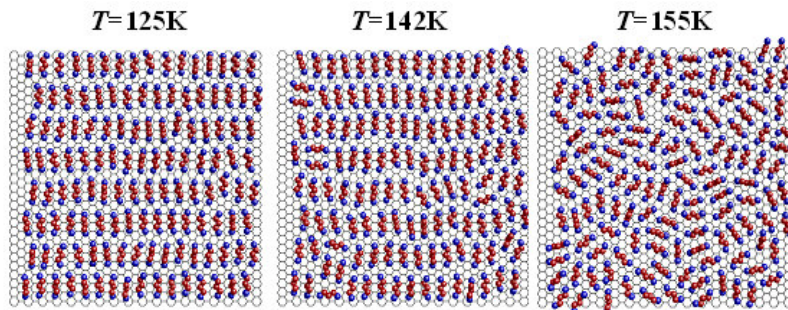
Parameter	Value
k_θ	62793.59 K/rad ²
θ_0	114°
c_0	1037.76 K
c_1	2426.07 K
c_2	81.64 K
c_3	-3129.46 K
c_4	-163.28 K
c_5	-252.73 K

Table III. Simulated unit-cell parameters, computational cell sizes, and numbers of molecules and atoms in simulations for pentane, heptane, and nonane monolayers. Note that a (*) refers to a fully commensurate monolayer, in which cell parameters are taken from experimental work¹⁰. Other cell parameters are those proposed by Matthies⁶. Initial HB rotations for those monolayers given by Matthies is $\pm 3^\circ$ and $\pm 6^\circ$ for the C5 and C7 monolayers respectively.

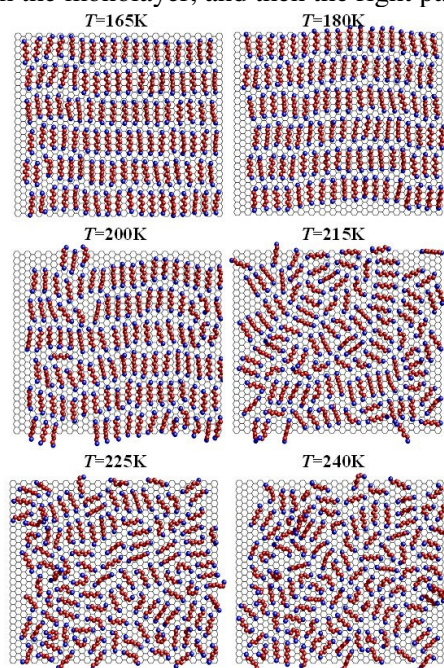
	a (Å)	b (Å)	cell size (Å)	N_m	N_a
Pentane	16.98	4.66	67.92 X 74.56	128	640
Pentane*	17.1	4.26	68.88 X 68.3	128	640
Heptane	21.9	4.57	65.7 X 73.12	96	672
Heptane*	22.0	4.26	66.0 X 76.68	108	756
Nonane*	27.0	4.26	81.0 X 68.16	96	864

Table IV. Melting transition temperatures (T_m) with respective uncertainty for each monolayer studied (including nonane) compared to experimental observations of melting temperatures^{6,10} in each monolayer (if this is studied). Fully commensurate monolayers (with unit cell parameters) are indicated with an asterisk (*).

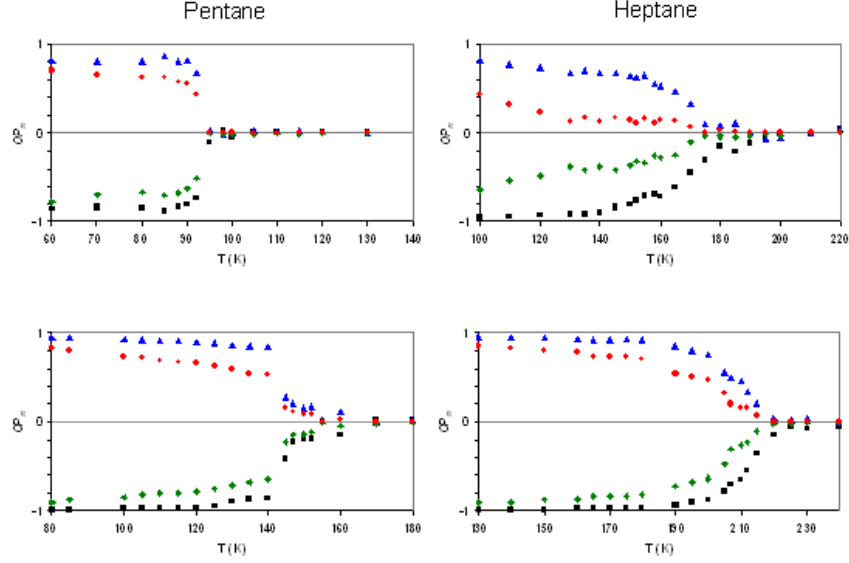
alkane monolayer	Simulated T_m	Experimental T_m
Pentane	$92 \pm 3\text{K}$	$99\text{-}105\text{K}^6$
Pentane*	$147 \pm 3\text{K}$	150K^7
Heptane	$178 \pm 5\text{K}$	$170 \pm 10\text{K}^6$
Heptane*	$218 \pm 5\text{K}$	206K^8
Nonane*	$255 \pm 3\text{K}$	N/A



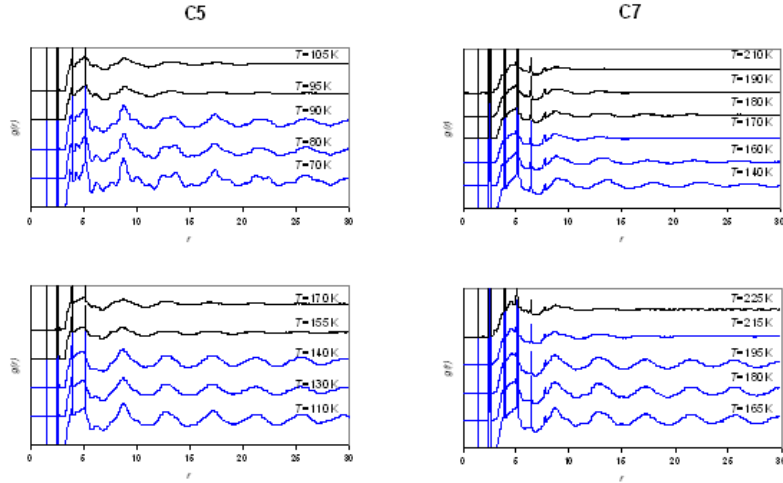
(color online) **Figure 1a.** Visual representation of the melting transition in (high coverage) pentane monolayers. The left panel is representative of the solid monolayer in the low-temperature solid phase. The middle panel shows a temperature point ca. 5K below the melting temperature, where there seems to be some disorder that is evident in the monolayer, and then the right panel shows the melted monolayer.



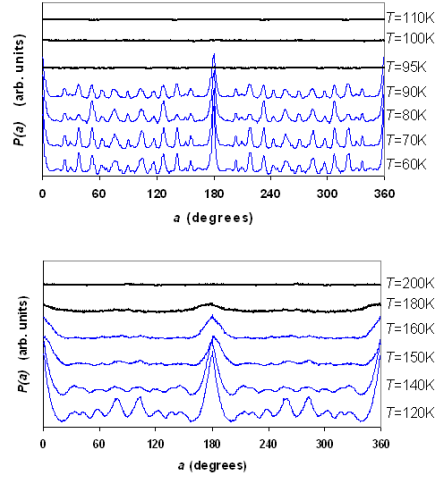
(color online) **Figure 1b.** A series of six snapshots of the melting transition in (high coverage) heptane monolayers. The top four snapshots correspond to temperature points before melting takes place, while the bottom two correspond to points after melting.



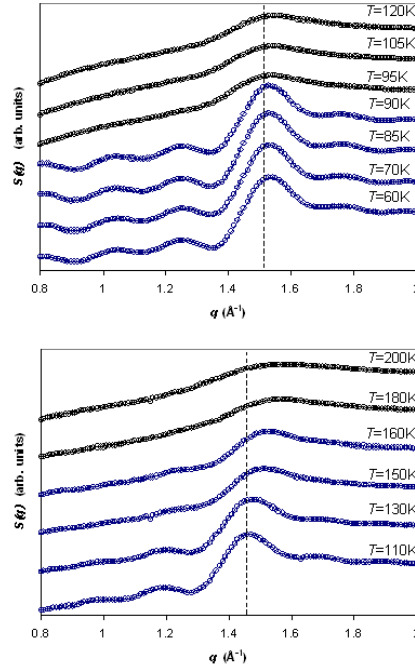
(color online) **Figure 2.** OP_n , with $n=2, 4, 6$, and 8 , for pentane monolayers (left two panels) and heptane monolayers (right two panels). In each panel, the corresponding symbol is: for $n=2$ (black squares), $n=4$ (blue triangles), $n=6$ (green diamonds), and $n=8$ (red circles). The monolayers with cell parameters given by Matthies⁶ are on the top two panels, and those with cell parameters given by Arnold et al.¹⁰ (for a fully commensurate monolayer) are in the bottom two panels.



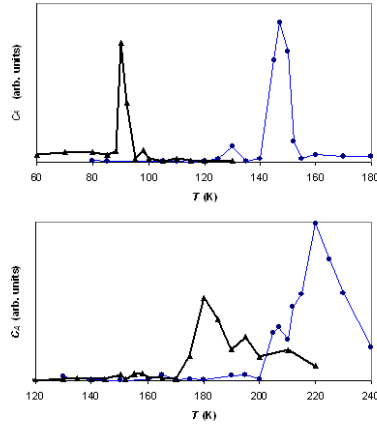
(color online) **Figure 3.** Atomic pair correlation function $g(r)$ for monolayers of C5 (pentane) and C7 (heptane) for various labeled temperature points. Lines that are colored blue correspond to points below the melting temperature, and those in black (bold) represent points after the melting temperature. (*note: temperature points compared to table IV can also be used to classify this). The top and bottom panels are situated (regarding the monolayers they represent) identical to in figure 2.



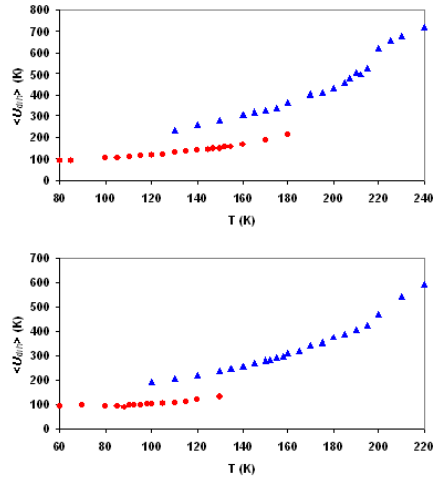
(color online) **Figure 4.** Bond-orientational distributions, $P(a)$, for 1st-5th neighbor shells for monolayers of pentane (top panel) and heptane (bottom panel) with unit cell parameters given by Matthies⁶. Note the very sudden loss of long-range orientational order between 90-95K in the pentane monolayer, and the more gradual loss of long-range orientational order in the heptane monolayer.



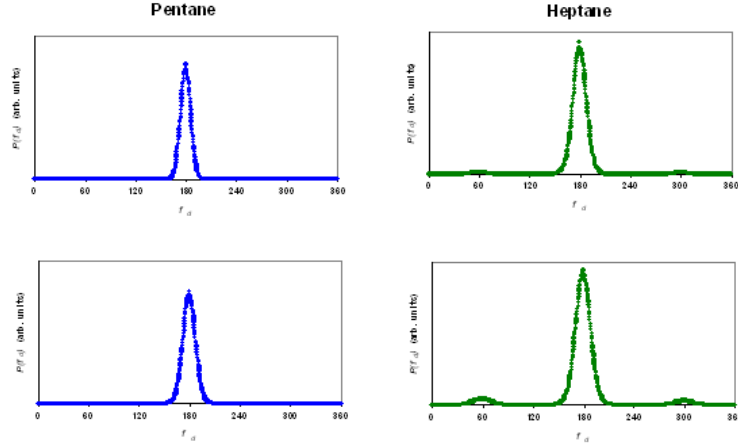
(color online) **Figure 5.** Static structure factors, $S(q)$, for pentane (top panel) and heptane (bottom panel) monolayers simulated from experimental observation by Matthies⁶. Note the slight shift to higher q observed for the middle peak in heptane monolayers, and the relatively strict positioning of the peak in pentane monolayers, even after melting.



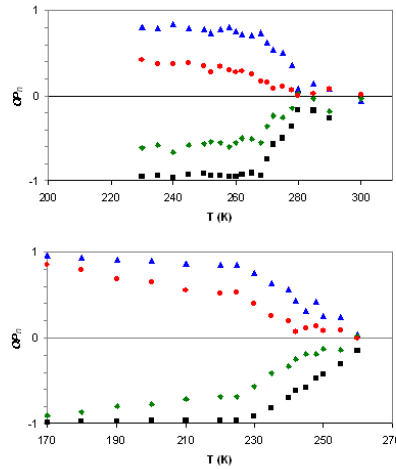
(color online) **Figure 6.** Specific heat at constant area, C_A , for monolayers of pentane (top) and heptane (bottom). The high coverage (fully commensurate)¹⁰ monolayers correspond to the (blue) diamonds (and blue lines), and the monolayers simulated from Matthies⁶ correspond to the (black) triangles (and bold lines). Notice the sharp features of the specific heats in both pentane monolayers, and the more rounded off nature of the specific heats in both heptane monolayers.



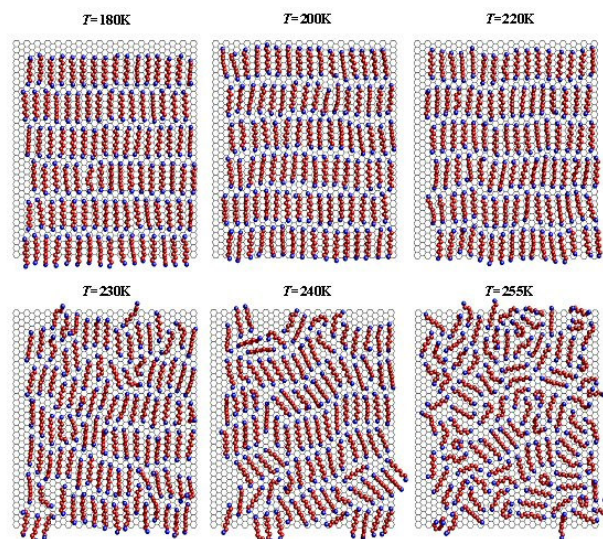
(color online) **Figure 7.** Average dihedral energy, $\langle U_{dih} \rangle$, for heptane (blue, triangles) and pentane (red, circles) monolayers. The monolayers with fully commensurate cell parameters¹⁰ are represented in the top panel, and the monolayers with unit-cell parameters given by Matthies⁶ are in the bottom panel.



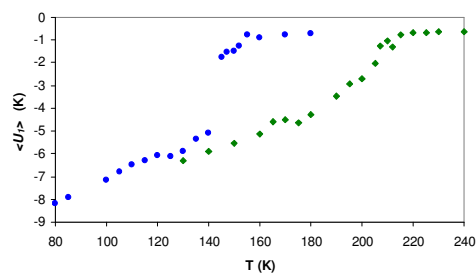
(color online) **Figure 8.** Dihedral angle distributions, $P(\varphi_d)$, for pentane monolayers (left panels, blue) and heptane monolayers (right panels, green). The top two panels represent unit-cell parameters as proposed by Matthies⁶. The bottom two panels are therefore those with (high coverage)¹⁰ fully commensurate monolayers.



(color online) **Figure 9.** Order parameters, OP_n , for (high coverage) heptane with the formation of gauche defects completely eliminated (top panel), and (high coverage) nonane monolayer (bottom panel). The top panel is fit to the same temperature range as in figure 2 for the high coverage heptane monolayer, for comparison. Labeling convention is the same as figure 5-2.



(color online) **Figure 10.** Snapshots of a high coverage nonane monolayer at six labeled temperature points. One can notice the same type of behavior that is present in figure 1b for heptane monolayers, as there is a significant amount of translational motion of the sublattices before melting.



(color online) **Figure 11.** Average corrugation potential energy, $\langle U_I \rangle$, per pseudoatom for high coverage monolayers of heptane (green, diamonds) and pentane (blue, circles). Notice the gradual nature of the increase for the heptane monolayer, but the very rapid succinct loss of (atomic) commensurability that takes place for the pentane monolayers.